

**1.5MHz Synchronous Step-down DC-DC Converter****AP3410****General Description**

The AP3410 is a high efficiency step-down DC-DC voltage converter. The chip operation is optimized by peak-current mode architecture with built-in synchronous power MOSFET switchers. The oscillator and timing capacitors are all built-in providing an internal switching frequency of 1.5MHz that allows the use of small surface mount inductors and capacitors for portable product implementations.

Integrated Soft Start (SS), Under Voltage Lock Out (UVLO), Thermal Shutdown Detection (TSD) and Short Circuit Protection are designed to provide reliable product applications.

The device is available in adjustable output voltage version ranging from 0.6V to  $0.9 \times V_{IN}$  when input voltage range is from 2.5V to 5.5V, and is able to deliver up to 1.2A.

The AP3410 is available in SOT-23-5 and DFN-2×2-6 packages.

**Features**

- High Efficiency Buck Power Converter
- Wide Input Voltage Range: 2.5V to 5.5V
- Adjustable Output Voltage: 0.6V to  $0.9 \times V_{IN}$
- Low  $R_{DS(ON)}$  Internal Switches: 200m $\Omega$  ( $V_{IN}=5V$ )
- Built-in Power Switches for Synchronous Rectification with High Efficiency
- Output Current: 1.2A
- Feedback Voltage: 600mV
- 1.5MHz Constant Frequency Operation
- Thermal Shutdown Protection
- Low Dropout Operation at 100% Duty Cycle
- No Schottky Diode Required
- Input Over Voltage Protection
- Output Over Voltage Protection
- Over Current Protection

**Applications**

- Post DC-DC Voltage Regulation
- PDA and Notebook Computer

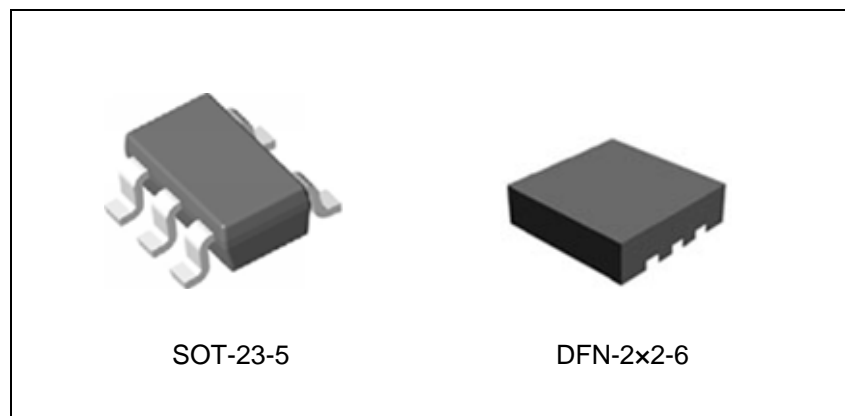


Figure 1. Package Types of AP3410

# 1.5MHz Synchronous Step-down DC-DC Converter

**AP3410**

## Pin Configuration

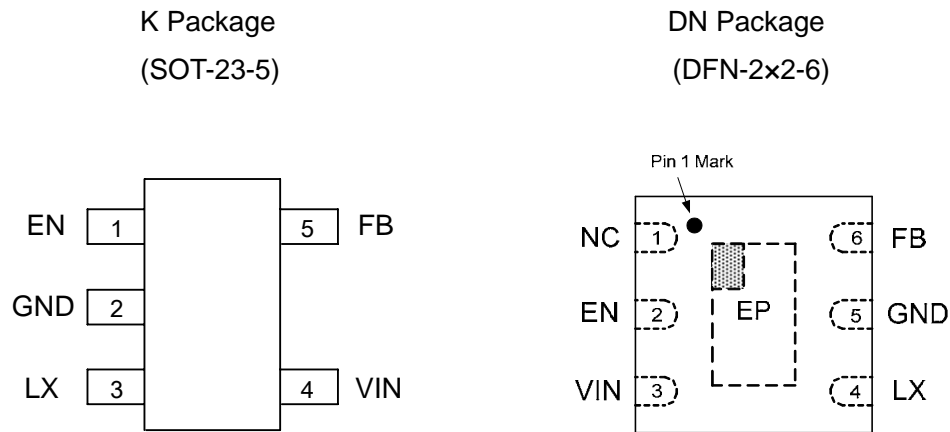


Figure 2. Pin Configuration of AP3410 (Top View)

## Pin Description

Pin Number		Pin Name	Function
SOT-23-5	DFN-2x2-6		
1	2	EN	Chip enable pin. Active high
2	5	GND	Ground pin
3	4	LX	Switch output pin
4	3	VIN	Power supply
5	6	FB	Feedback voltage of output
	1	NC	No internal connection

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AP3410

## Functional Block Diagram

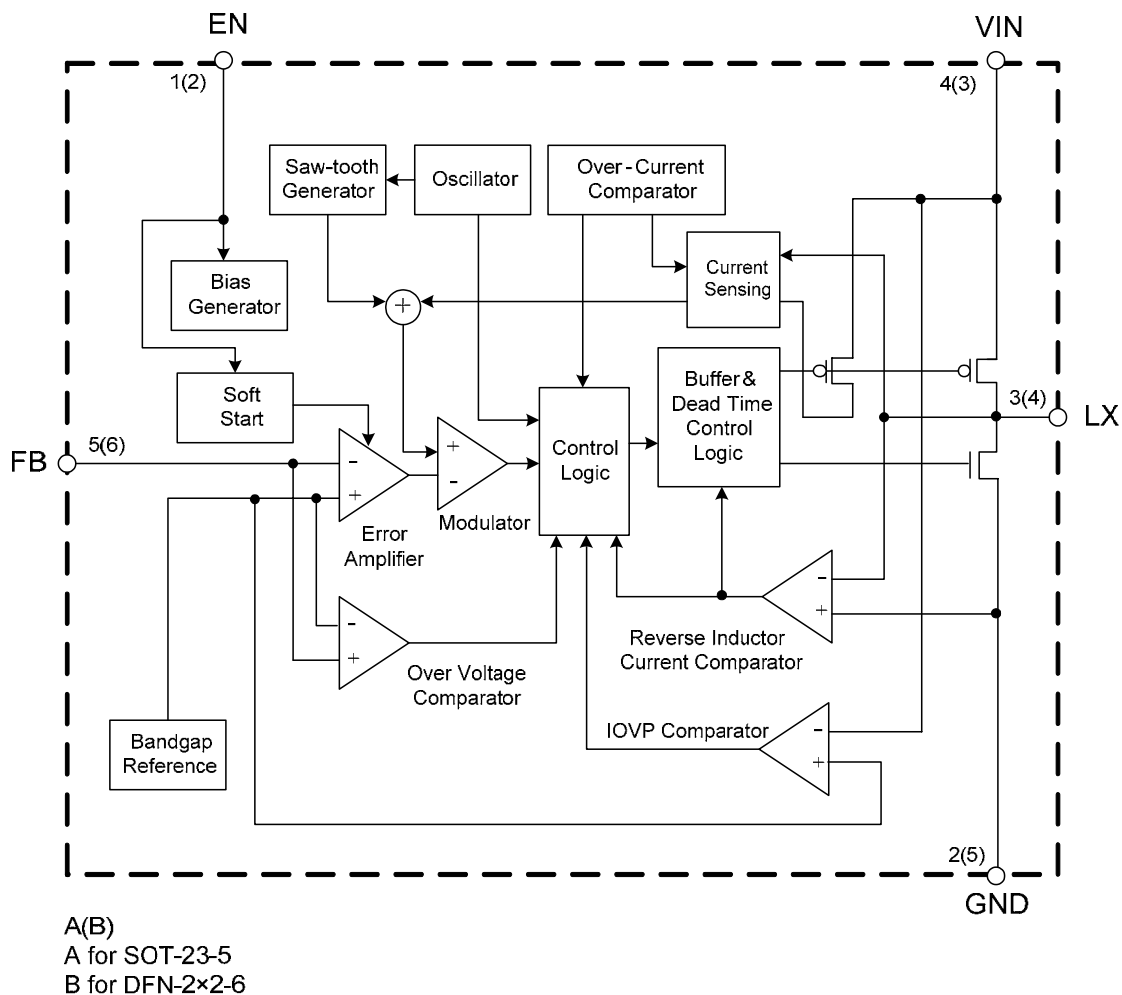
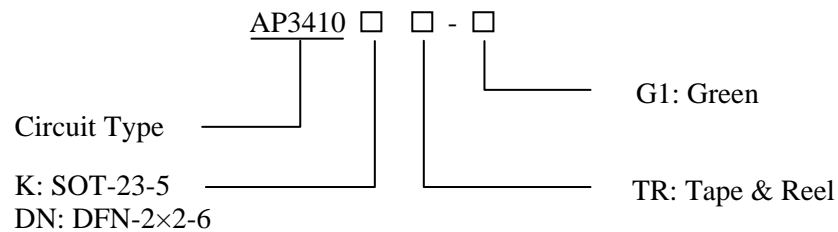


Figure 3. Functional Block Diagram of AP3410

**1.5MHz Synchronous Step-down DC-DC Converter****AP3410****Ordering Information**

Package	Temperature Range	Part Number	Marking ID	Packing Type
SOT-23-5	-40 to 85°C	AP3410KTR-G1	GHW	Tape & Reel
DFN-2×2-6	-40 to 85°C	AP3410DNTR-G1	CJ	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.

**Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value		Unit
Input Voltage for the MOSFET Switch	$V_{IN}$	0 to 6.0		V
Enable Input Voltage	$V_{EN}$	-0.3 to $V_{IN}+0.3$		V
LX Pin Switch Current	$I_{LX}$	1.8		A
Power Dissipation (on PCB, $T_A=25^{\circ}\text{C}$ )	$P_D$	SOT-23-5	0.4	W
		DFN-2×2-6	1.89	
Thermal Resistance (Junction to Ambient, Simulation)	$\theta_{JA}$	SOT-23-5	250	$^{\circ}\text{C}/\text{W}$
		DFN-2×2-6	53	
Thermal Resistance (Junction to Case, Simulation)	$\theta_{JC}$	SOT-23-5	130	$^{\circ}\text{C}/\text{W}$
Operating Junction Temperature	$T_J$	155		$^{\circ}\text{C}$
Storage Temperature	$T_{STG}$	-55 to 150		$^{\circ}\text{C}$
Operating Temperature	$T_{OP}$	-40 to 85		$^{\circ}\text{C}$
ESD (Machine Model)	$V_{MM}$	200		V
ESD (Human Body Model)	$V_{HBM}$	2000		V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

**1.5MHz Synchronous Step-down DC-DC Converter****AP3410****Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Supply Input Voltage	$V_{IN}$	2.5	5.5	V
Operating Ambient Temperature	$T_A$	-40	85	°C
Operating Junction Temperature	$T_J$	-40	125	°C

**Electrical Characteristics**

$V_{IN}=V_{EN}=5V$ ,  $V_{OUT}=1.2V$ ,  $V_{FB}=0.6V$ ,  $L=2.2\mu H$ ,  $C_{IN}=4.7\mu F$ ,  $C_{OUT}=10\mu F$ ,  $T_A=25^\circ C$ , unless otherwise specified.

Parameters	Symbol	Conditions	Min	Typ	Max	Unit
Input Voltage Range	$V_{IN}$		2.5		5.5	V
Shutdown Current	$I_{OFF}$	$V_{EN}=0$			0.1	$\mu A$
Active Current	$I_{ON}$	$V_{FB}=0.55V$		220		$\mu A$
Regulated Feedback Voltage	$V_{FB}$		0.588	0.6	0.612	V
Regulated Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	$V_{IN}=2.5V$ to $5.5V$ , $I_{OUT}=0$ to $1.2A$	-3		3	%
Peak Inductor Current	$I_{PK}$		1.5	1.9		A
Oscillator Frequency	$f_{OSC}$	$V_{IN}=2.5V$ to $5.5V$	1.2	1.5	1.8	MHz
PMOSFET $R_{DS(ON)}$	$R_{DS(ON)P}$	$V_{IN}=5V$		200		$m\Omega$
NMOSFET $R_{DS(ON)}$	$R_{DS(ON)N}$	$V_{IN}=5V$		200		$m\Omega$
EN High Level Input Voltage	$V_{EN\_H}$		1.5			V
EN Low Level Input Voltage	$V_{EN\_L}$				0.4	V
EN Input Current	$I_{EN}$				0.1	$\mu A$
Soft Start Time	$t_{SS}$			400		$\mu s$
Maximum Duty Cycle	$D_{MAX}$		100			%
Under Voltage Lock Out Threshold	$V_{UVLO}$	Rising		2.3		V
		Falling		2.1		
		Hysteresis		0.2		
Thermal Shutdown	$T_{SD}$	Hysteresis= $30^\circ C$		155	160	°C

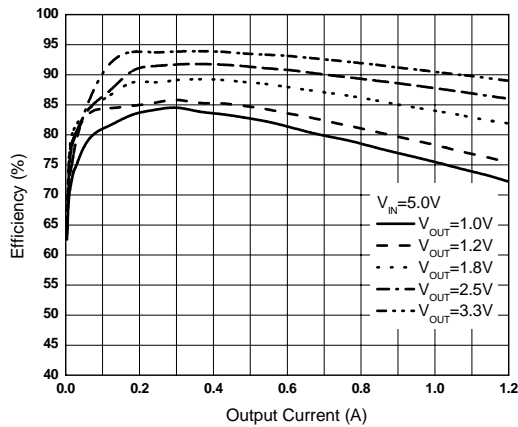
**1.5MHz Synchronous Step-down DC-DC Converter****AP3410****Typical Performance Characteristics** $V_{IN}=5V$ ,  $T_A=25^{\circ}C$ , unless otherwise noted.

Figure 4. Efficiency vs. Output Current

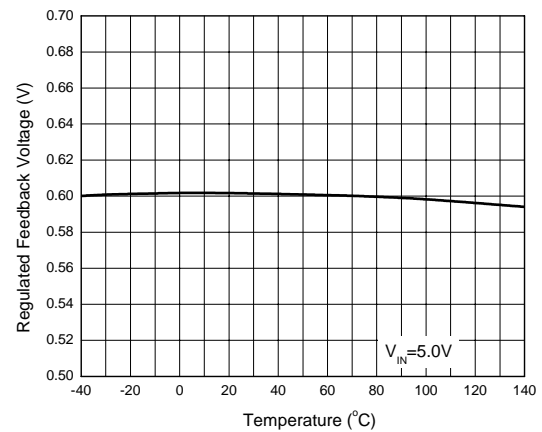
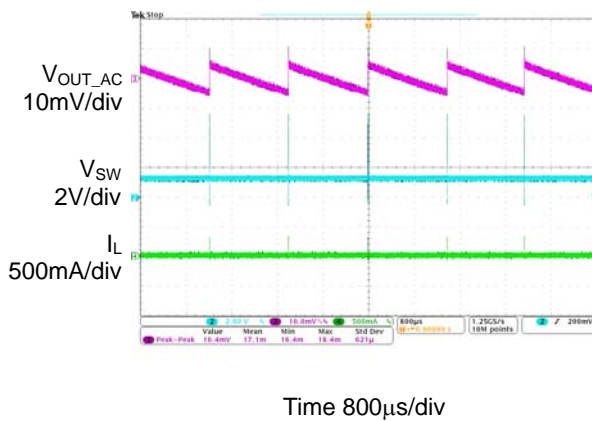
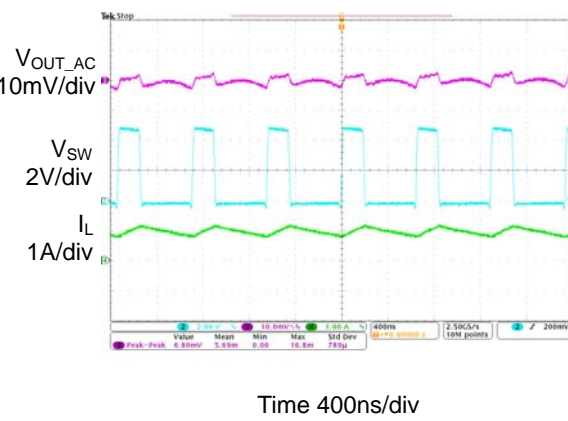


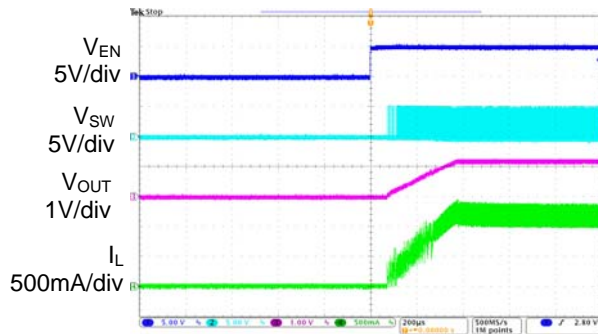
Figure 5. Regulated Feedback Voltage vs. Temperature

Figure 6. Output Ripple ( $I_{OUT}=0A$ )Figure 7. Output Ripple ( $I_{OUT}=1.2A$ )

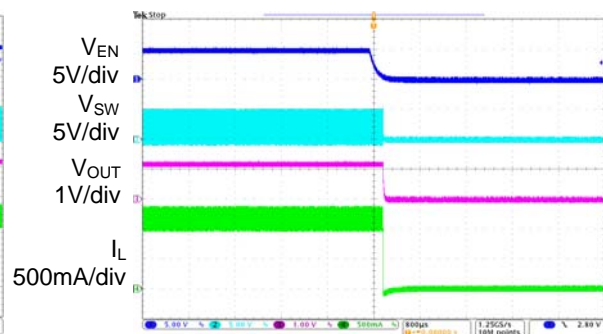
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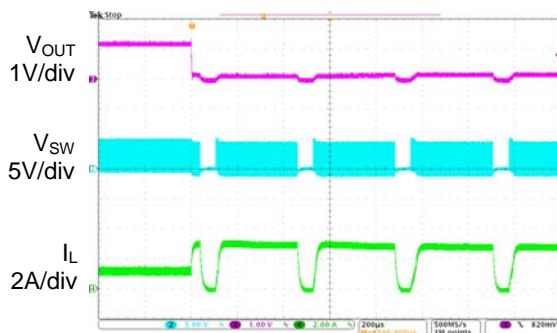
## Typical Performance Characteristics (Continued)

 $V_{IN}=5V$ ,  $T_A=25^{\circ}C$ , unless otherwise noted.


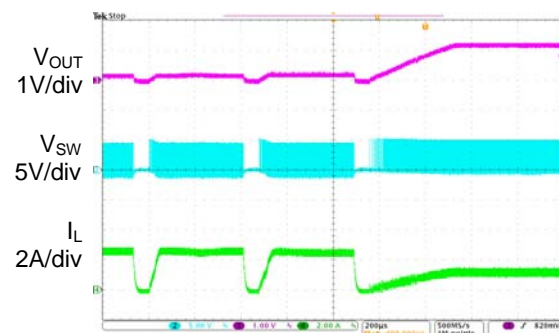
Time 200µs/div

Figure 8. Enable Turn On ( $I_{OUT}=1.2A$ )


Time 800µs /div

Figure 9. Enable Turn Off ( $I_{OUT}=1.2A$ )


Time 200µs/div

Figure 10. Short Circuit Protection ( $I_{OUT}=1.2A$ )


Time 200µs /div

Figure 11. Short Circuit Protection Recovery ( $I_{OUT}=1.2A$ )

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# AP3410

## Typical Application

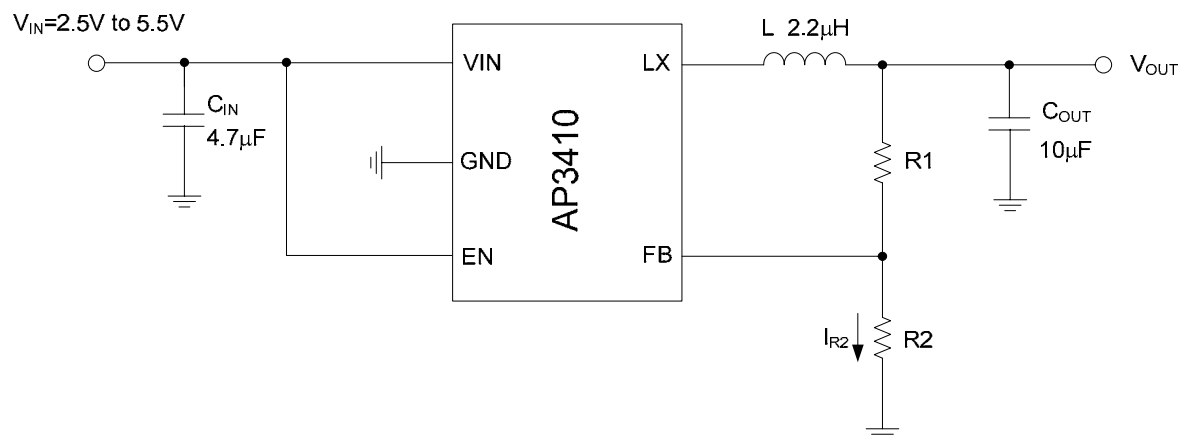
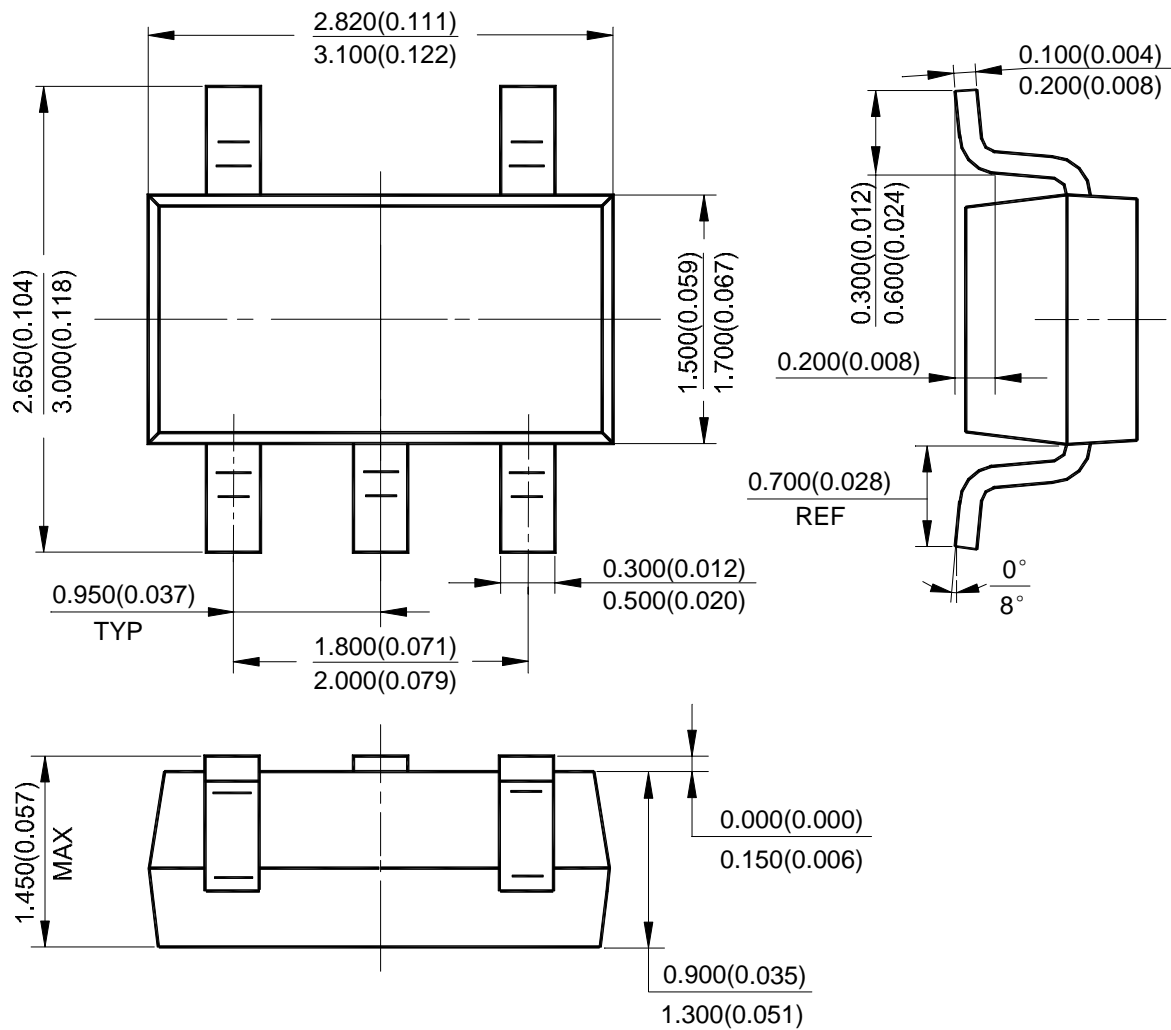


Figure 12. Typical Applications of AP3410

## Table 1. Component Guide

$V_{OUT}$ (V)	$R1$ (kΩ)	$R2$ (kΩ)	$L$ (μH)
3.3	450	100	2.2
2.5	320	100	2.2
1.8	200	100	2.2
1.2	100	100	2.2
1.0	66	100	2.2



**1.5MHz Synchronous Step-down DC-DC Converter**
**AP3410**
**Mechanical Dimensions**
**SOT-23-5**
**Unit: mm(inch)**


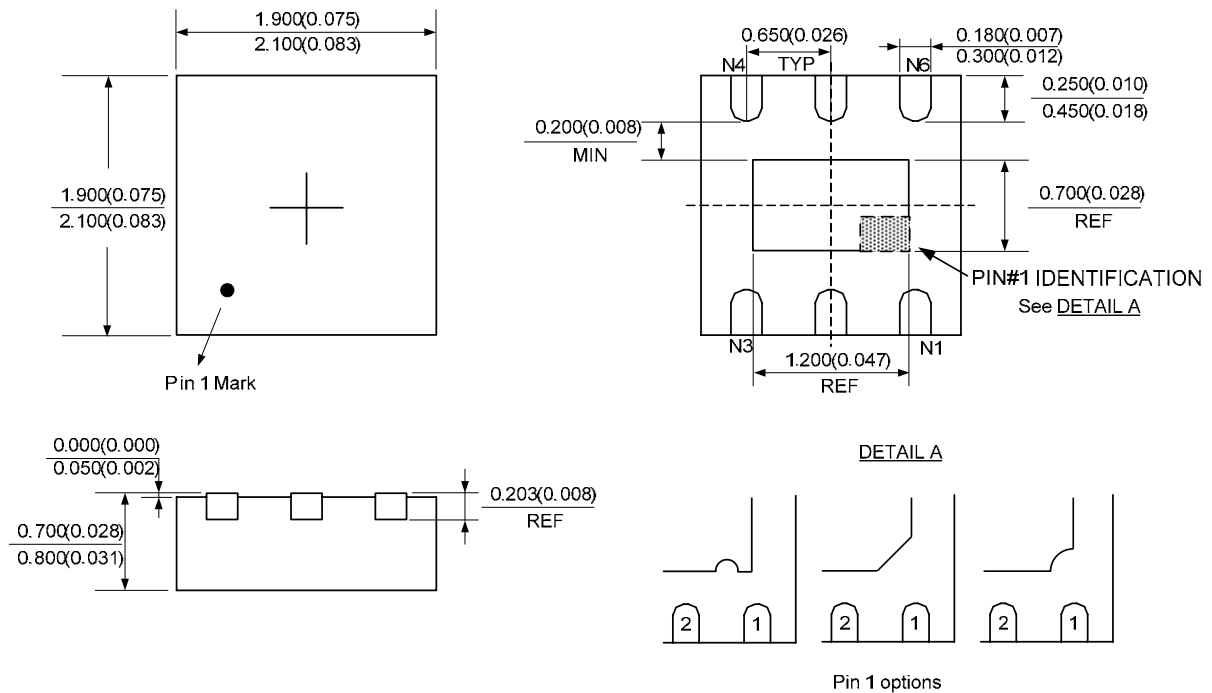
# 1.5MHz Synchronous Step-down DC-DC Converter

AP3410

## Mechanical Dimensions (Continued)

DFN-2x2-6

Unit: mm(inch)





## **BCD Semiconductor Manufacturing Limited**

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#### **MAIN SITE**

##### **- Headquarters**

##### **BCD (Shanghai) Micro-electronics Limited**

No. 1600, Zi Xing Road, Shanghai ZiZhu Science-based Industrial Park, 200241, P. R. C.  
Tel: +86-021-2416-2266, Fax: +86-021-2416-2277

##### **- Wafer Fab**

##### **Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd.**

800 Yishan Road, Shanghai 200233, China  
Tel: +021-6485-1491, Fax: +86-021-5450-0008

#### **REGIONAL SALES OFFICE**

##### **Shenzhen Office**

##### **Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office**

Unit A Room 1203, Skyworth Bldg., Gaoxin Ave. 1.S., Nanshan District  
Shenzhen 518057, China  
Tel: +86-0755-8660-4900, Fax: +86-0755-8660-4958

##### **Taiwan Office (Taipei)**

##### **BCD Semiconductor (Taiwan) Company Limited**

3F, No.17, Lane 171, Sec. 2, Jiu-Zong Rd., Nei-Hu Dist., Taipei(114), Taiwan, R.O.C  
Tel: +886-2-2656 2808  
Fax: +886-2-2656-2806/26562950

##### **Taiwan Office (Hsinchu)**

##### **BCD Semiconductor (Taiwan) Company Limited**

8F, No.176, Sec. 2, Gong-Dao 5th Road, East District  
HsinChu City 300, Taiwan, R.O.C  
Tel: +886-3-5160181, Fax: +886-3-5160181

##### **USA Office**

##### **BCD Semiconductor Corp.**

48460 Kato Road, Fremont, CA 94538, USA  
Tel: +1-510-668-1950  
Fax: +1-510-668-1990

##### **Korea Office**

##### **BCD Semiconductor Limited Korea office.**

Room 101-1112, Digital-Empire II, 486 Sin-dong,  
Yeongtong-Gu, Suwon-city, Gyeonggi-do, Korea  
Tel: +82-31-695-8430